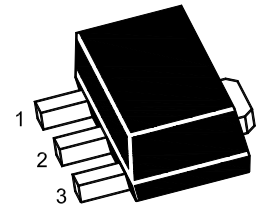


MPSA92U

PNP Silicon Expitaxial Planar Transistor



1.Base 2.Collector 3.Emitter
SOT-89 Plastic Package

Applications

- High voltage switching and amplifier

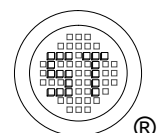
Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{\text{CBO}}$	300	V
Collector Emitter Voltage	$-V_{\text{CEO}}$	300	V
Emitter Base Voltage	$-V_{\text{EBO}}$	5	V
Collector Current	$-I_{\text{C}}$	500	mA
Power Dissipation	P_{tot}	500	mW
Junction Temperature	T_{j}	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Thermal Characteristics

Parameter	Symbol	Max.	Unit
Thermal Resistance from Junction to Ambient ¹⁾	$R_{\theta\text{JA}}$	250	$^\circ\text{C/W}$

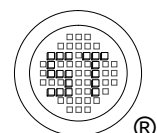
¹⁾ Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.



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Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $-I_C = 1\text{ mA}$, $-V_{CE} = 10\text{ V}$ at $-I_C = 10\text{ mA}$, $-V_{CE} = 10\text{ V}$ at $-I_C = 30\text{ mA}$, $-V_{CE} = 10\text{ V}$	h_{FE} h_{FE} h_{FE}	25 40 25	- - -	- - -
Collector Base Cutoff Current at $-V_{CB} = 200\text{ V}$	$-I_{CBO}$	-	0.25	μA
Emitter Base Cutoff Current at $-V_{EB} = 3\text{ V}$	$-I_{EBO}$	-	0.1	μA
Collector Base Breakdown Voltage at $-I_C = 100\text{ }\mu\text{A}$	$-V_{(BR)CBO}$	300	-	V
Collector Emitter Breakdown Voltage at $-I_C = 1\text{ mA}$	$-V_{(BR)CEO}$	300	-	V
Emitter Base Breakdown Voltage at $-I_E = 100\text{ }\mu\text{A}$	$-V_{(BR)EBO}$	5	-	V
Collector Emitter Saturation Voltage at $-I_C = 20\text{ mA}$, $-I_B = 2\text{ mA}$	$-V_{CE(sat)}$	-	0.5	V
Base Emitter Saturation Voltage at $-I_C = 20\text{ mA}$, $-I_B = 2\text{ mA}$	$-V_{BE(sat)}$	-	0.9	V
Gain Bandwidth Product at $-I_C = 10\text{ mA}$, $-V_{CE} = 20\text{ V}$, $f = 100\text{ MHz}$	f_T	50	-	MHz
Collector Output Capacitance at $-V_{CB} = 20\text{ V}$, $f = 1\text{ MHz}$	C_{ob}	-	6	pF



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Electrical Characteristics Curves

Fig. 1 Output Characteristics Curve

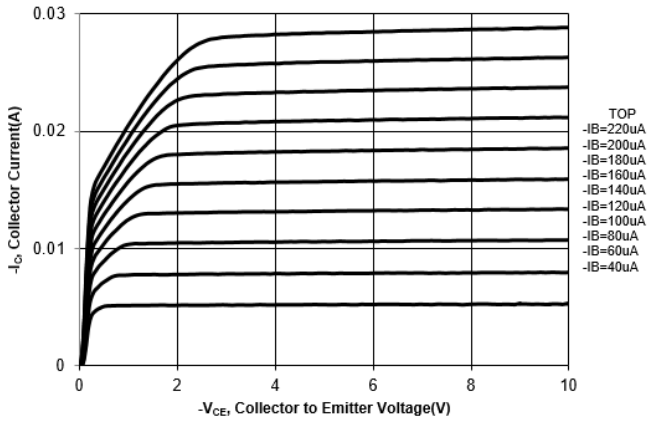


Fig. 2 Collector Current vs. Base to Emitter Voltage

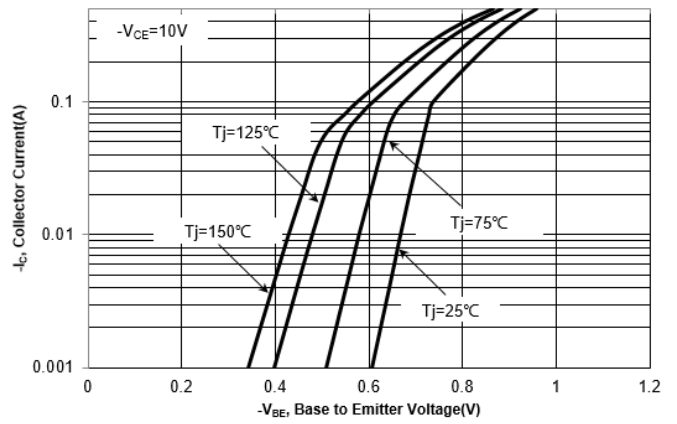


Fig. 3 DC Current Gain vs. Collector Current

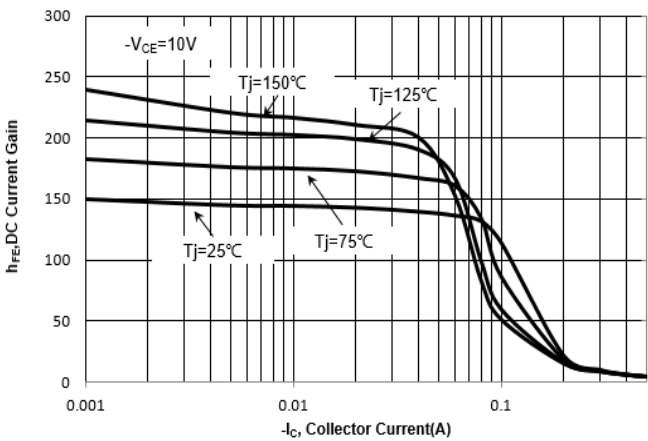
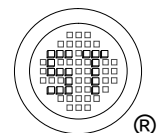
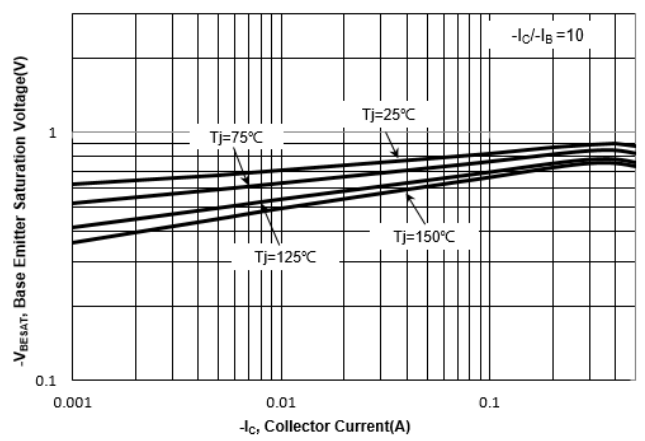


Fig. 4 V_{BESAT} vs. Collector Current



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Electrical Characteristics Curves

Fig. 5 V_{CESAT} vs. Collector Current

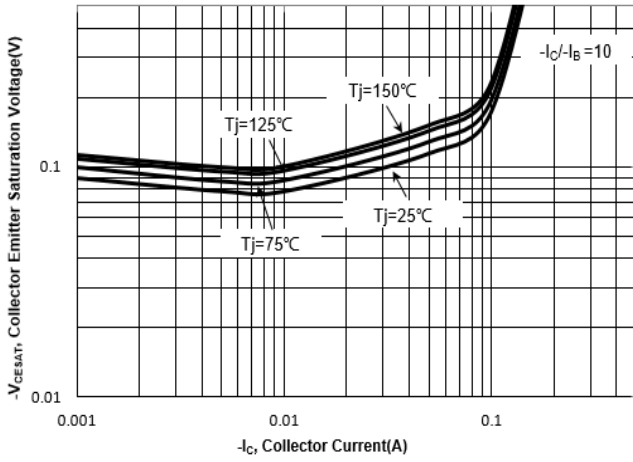


Fig. 6 Output Capacitance

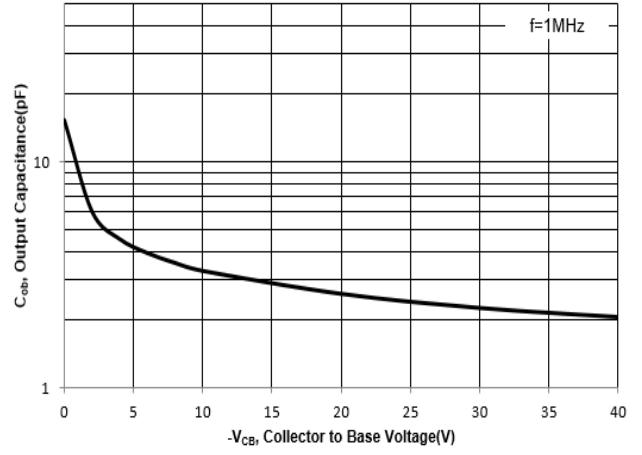
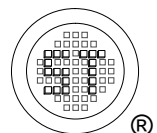
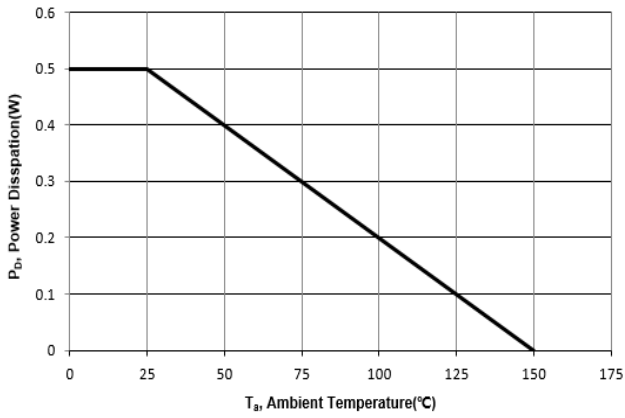


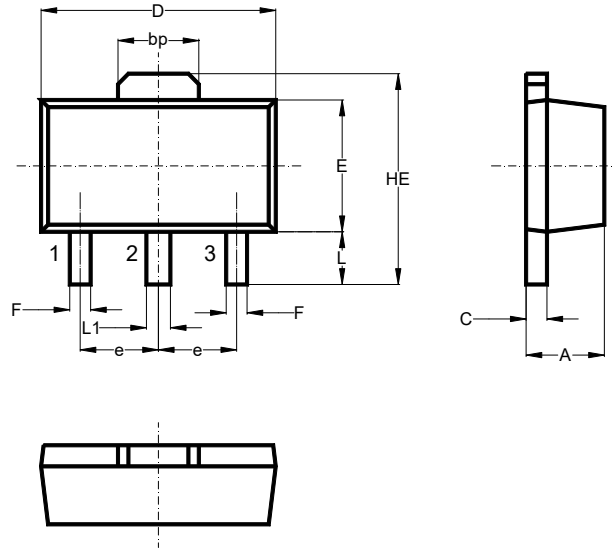
Fig. 7 Power Derating Curve



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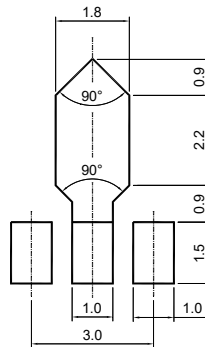
Package Outline (Dimensions in mm)

SOT-89



Unit	A	bp	C	D	E	F	HE	e	L	L1
mm	1.6	1.60	0.5	4.6	2.6	0.45	4.25	1.5	1.05	0.51
	1.4	1.50	0.3	4.4	2.4	0.35	3.75	typ.	0.95	0.41

Recommended Soldering Footprint



Packing information

Package	Tape Width (mm)	Pitch		Reel Size		Per Reel Packing Quantity
		mm	inch	mm	inch	
SOT-89	12	8 ± 0.1	0.315 ± 0.004	178	7	1,000
				330	13	4,000

Marking information

" MPSA92U " = Part No.
 " YM " = Date Code Marking
 " Y " = Year
 " M " = Month
 Font type: Arial

